

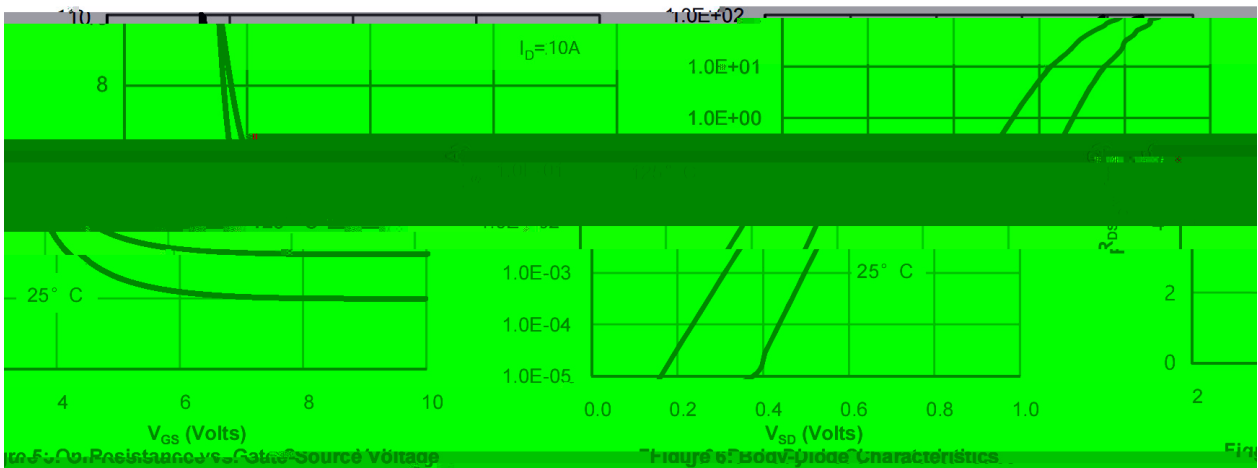
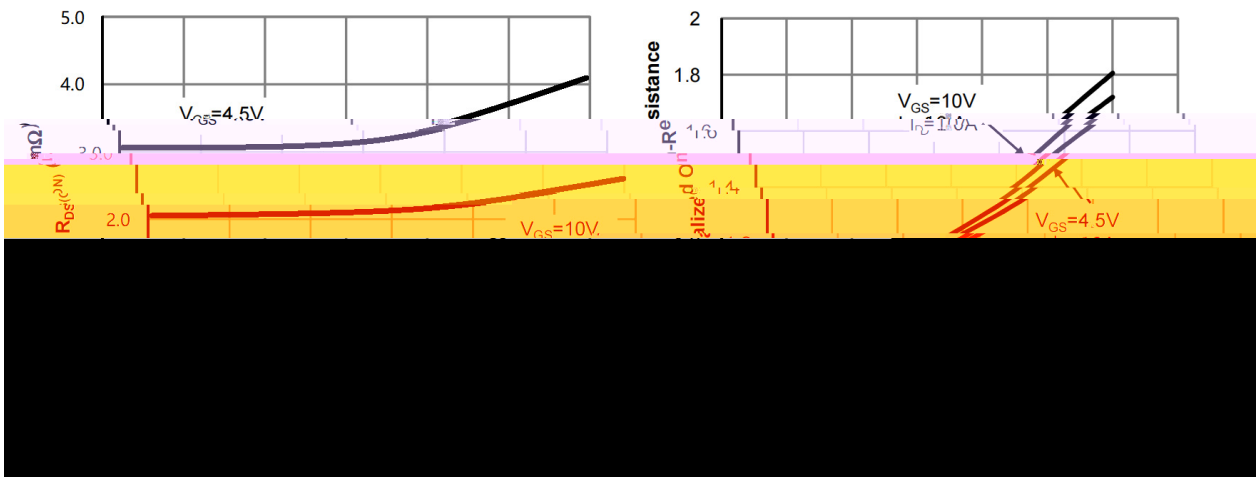
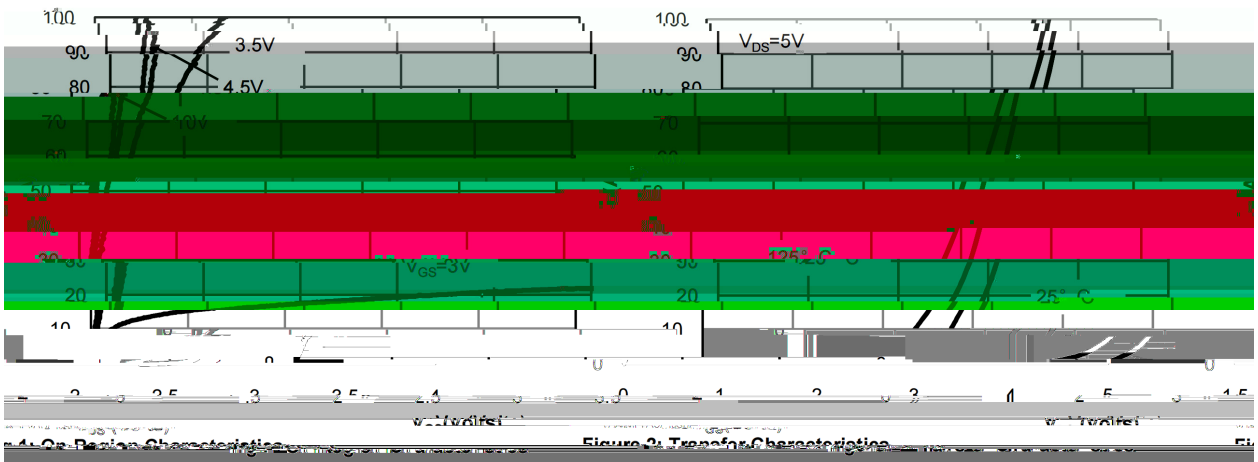
Rev.B Dec.-2024

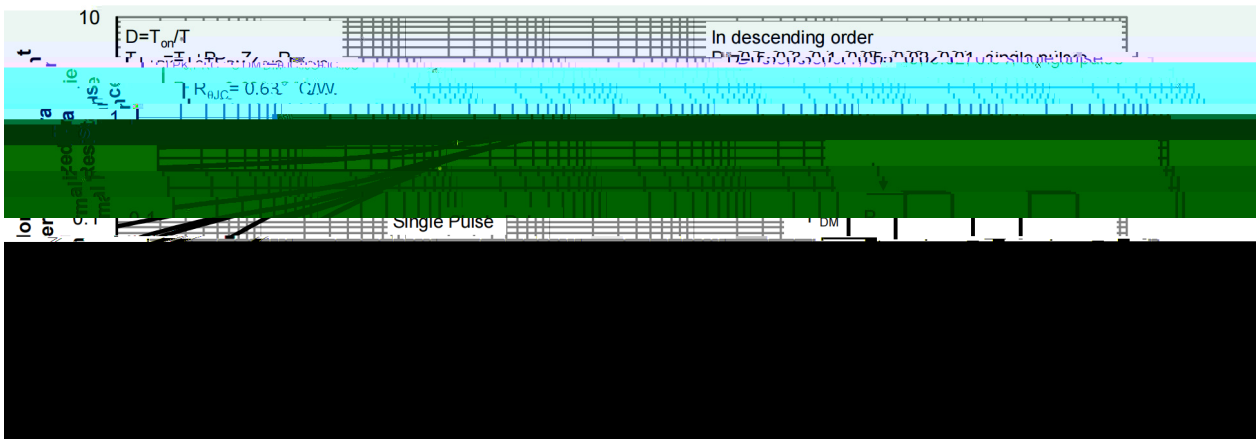
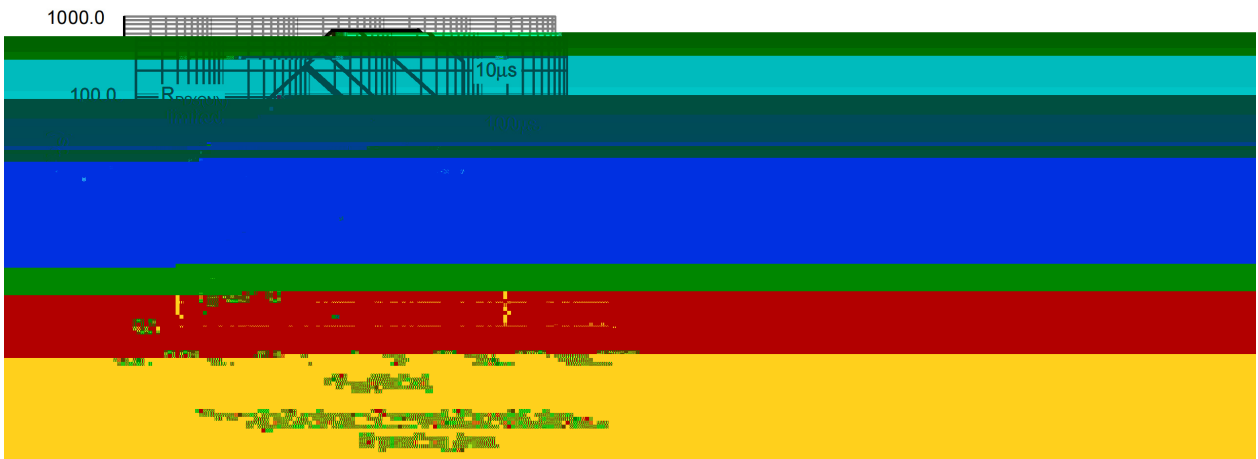
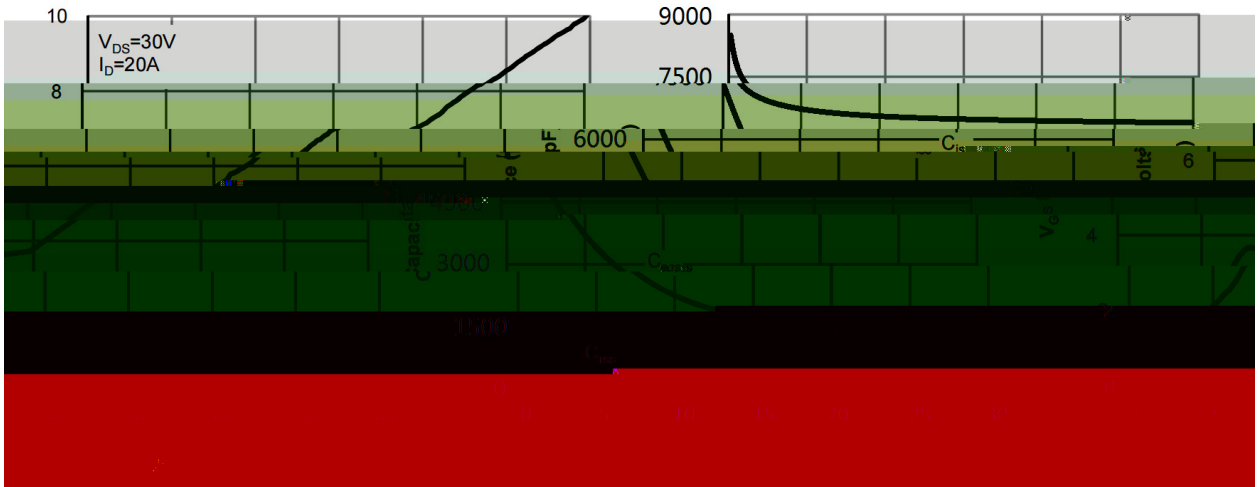
TO-220 N
N-CHANNEL MOSFET in a TO-220 Plastic Package.

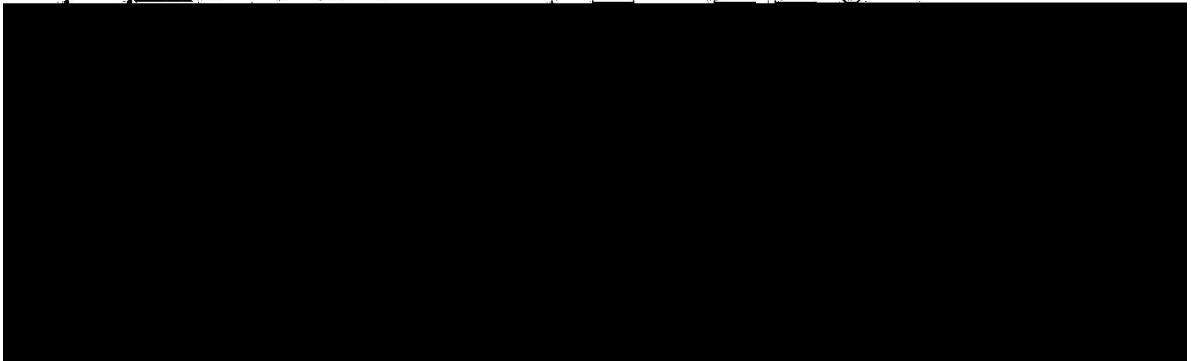
V_{DS}

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DSS}	60	V
Drain Current	$I_D(T_C=25)$	225	A
Pulsed Drain Current	I_{DM}	646	A
Gate-Source Voltage	V_{GS}	± 20	V
Single Pulsed Avalanche Energy L=0.5mH	E_{AS}	380	mJ
Avalanche Current	I_{AS}	30.8	A
Total Power Dissipation	$P_D(T_C=25)$	125	W

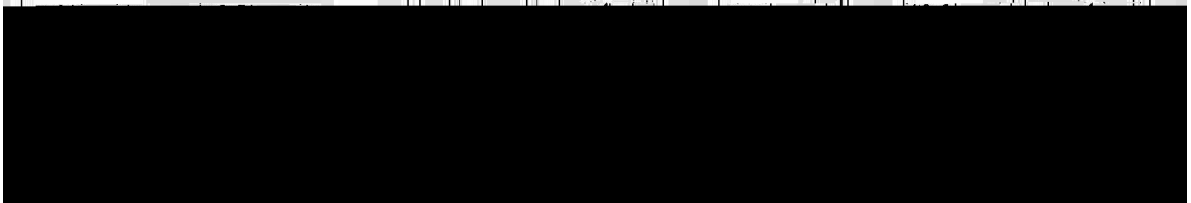
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Total Gate Charge	$Q_g(10V)$	$V_{GS}=10V$ $V_{DS}=30V$ $I_D=20A$		60		nC
Total Gate Charge	$Q_g(4.5V)$			23		
Gate Source Charge	Q_{gs}			16		
Gate Drain Charge	Q_{gd}			3		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=20V$ $R_L=1$ $R_{GEN}=3$		13		ns
Turn-On Rise Time	t_r			4		
Turn-Off Delay Time	$t_{d(off)}$			47		
Turn-Off Fall Time	t_f			6.5		

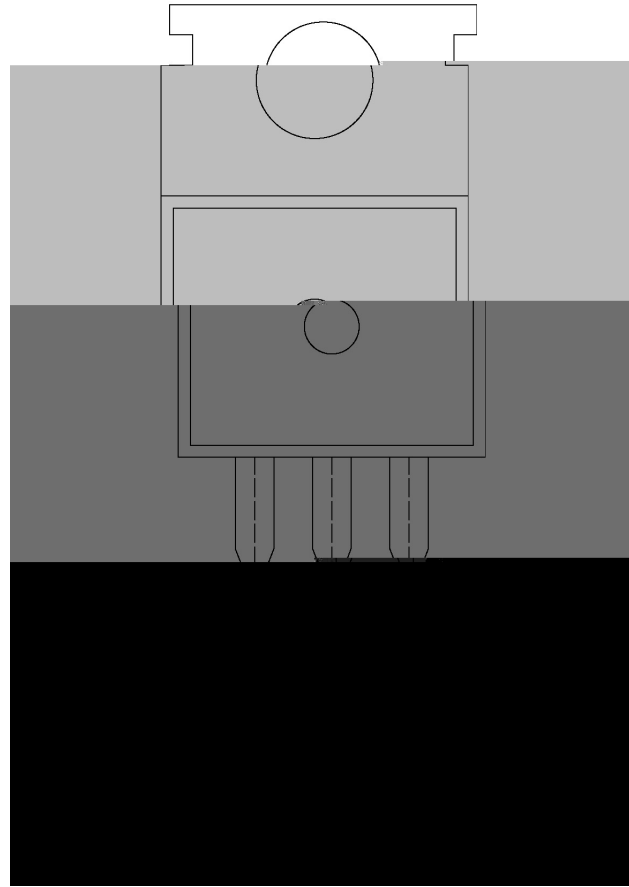






	Symbol	Min	Max	Symbol	Min	Max
6.7	A	9.8	10.2	C	12	14
9.4	R	3.56	3.64	B	6.3	
2.6	b	12.6	13.6	C1	2.2	





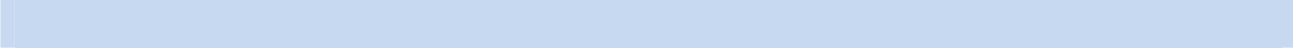
91

') ' N ' 6J

Note:

BR: Company Code

N o t e : 7



1	25	150	60	90sec;	Note:	1.Preheating:25~150 , Time:60~90sec.
2	255±5			5±0.5sec;		2.Peak Temp.:255±5 , Duration:5±0.5sec.
3			2	10		